



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s):

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Daniel C. Guterman and Sanjay Mehrotra

Title:

Soft Errors Handling in EEprom Devices

Serial No.:

08/908,265

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M-10202-3C US

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San Francisco, California May 9, 2002

BOX AFTER FINAL COMMISSIONER FOR PATENTS Washington, D. C. 20231

AMENDMENT AFTER FINAL

Dear Sir:

Responsive to the Official Action mailed on February 12, 2002, setting a response period expiring on May 12, 2002, applicant responds to the Official Action as follows:

In the Claims

Please and the following new claims:

--45. A method of operating a memory device having a plurality of memory

cells, comprising:

generating a first read voltage;

applying\said first read voltage to a terminal of a first cell of the plurality of

memory cells;

generating a first read result in response to said applying said first read voltage;

generating a second read voltage;

applying said second read voltage to said terminal of said first cell;

generating a second read result in response to said applying said first read

voltage; and

determining from said first and second read results whether data storage of the

memory device is deteriorated.

866523 v1 / PF-OA [Rev. 000913]

Serial No. 08/908,265

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